- A method of designing a metamaterial structure having a required
   permeability at a predetermined frequency, the metamaterial structure including a frequency selective surface located proximate to an electrically conductive layer, the
   method comprising:
- relating the required permeability to a required surface impedance of the apparatus at the predetermined frequency; and
- configuring the metamaterial structure so as to obtain the required surface metamaterial structure so as to obtain the required surface impedance, the apparatus thereby having the required permeability.
- 2. The method of claim 1, wherein the required permeability includes a required real permeability, the required surface impedance includes a required surface reactance, the required real permeability being related to the required surface reactance.
- The method of claim 1, wherein the required permeability includes a
   required imaginary permeability, the required surface impedance includes a required surface resistance, the required imaginary permeability being related to the required
   surface resistance.
- 4. The method of claim 1, wherein configuring the metamaterial structure so as
  2 to obtain the required surface impedance includes selecting a frequency selective surface
  having a resonance frequency proximate to the predetermined frequency.
- 5. The method of claim 1, wherein configuring the metamaterial structure so as to obtain the required surface impedance includes optimizing the frequency selective surface using an optimization algorithm.
- 6. The method of claim 5, wherein the optimization algorithm is a genetic 2 algorithm.

- The method of claim 1, wherein the frequency selective surface is disposed
   on a first side of the a dielectric substrate, and the electrically conductive layer is disposed on a second side of the dielectric substrate, the dielectric substrate having a
   dielectric thickness substantially less than the wavelength of electromagnetic radiation at the predetermined frequency.
- 8. An electromagnetic device including the metamaterial structure designed by the method of claim 1.
- 9. A method of designing a metamaterial structure having the properties of a ferrite film supported on a conducting ground plane, the metamaterial structure including a high impedance frequency selective surface, the method comprising:
- 4 relating a required permeability of the metamaterial structure to a surface impedance of the metamaterial structure,
- the required permeability having a required real component of permeability denoted  $\mu'_r$ , the surface impedance having a surface reactance denoted  $X_{s_1}$ , wherein

$$\mu_r' = \frac{X_{S1}}{\eta_0 \beta_0 d} ,$$

the value of surface reactance being chosen so as to provide the required real component of permeability.

10. The method of claim 9, wherein the required permeability further includes a required imaginary component  $\mu_r''$ , the required surface impedance having a surface resistance  $R_{S1}$ , wherein

$$\mu_r'' = \frac{R_{S1}}{\eta_0 \beta_0 d}$$

the value of surface resistance being chosen so as to provide the imaginary component of permeability.

- 11. The method of 9, wherein the value of surface reactance is chosen using
  2 electromagnetic modeling of the metamaterial structure, the metamaterial structure being configured to provide the value of surface reactance.
- 12. The method of claim 11, wherein an optimization algorithm is used to configure the metamaterial structure so as to provide the value of surface reactance.
- 13. The method of claim 11, wherein the optimization algorithm is a genetic 2 algorithm.
- 14. The method of claim 9, wherein the required real component of permeability2 is negative.
- 15. A structure providing a required permeability at a predetermined frequency,
  2 the structure comprising:
- a dielectric substrate, having a first side and a second side, and having a dielectric thickness and a dielectric constant;
- an electrically conducting layer disposed on the first side of the dielectric substrate; and
- a frequency selective surface disposed on the second side of the dielectric 8 substrate,
- wherein the surface impedance of the structure at the operating frequency is selected so as to provide the required permeability.
- The structure of claim 15, wherein the frequency selective surface includes a
   two-dimensional array of conducting elements.
- 17. The structure of claim 16, wherein the structure has the properties of a ferrite film.

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- 18. The structure of claim 15, wherein an optimization technique is used to 2 select the surface impedance.
- 19. The structure of claim 15, wherein the structure is an electromagnetic 2 absorber.
  - 20. An antenna including the structure of claim 15.
  - 21. A microwave device including the structure of claim 15.